NSN 5961-01-107-8668

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Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-107-8668 **Inclosure Material:** Ceramic and plastic **Overall Length:** 0.570 inches **Overall Height:** 0.200 inches **Overall Width:** 0.300 inches **Component Name And Quantity:** 16 semiconductor device diode **Mounting Method:** Press fit **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon all semiconductor device diode **Voltage Rating In Volts Per Characteristic:** 65.0 reverse voltage, peak all semiconductor device diode **Current Rating Per Characteristic:** 500.00 milliamperes source cutoff current preset all semiconductor device diode **Power Rating Per Characteristic:** 700.0 milliwatts small-signal input power, common-collector preset all semiconductor device diode **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius ambient air **Special Features:** All semiconductor device diode junction pattern arrangement: pn **Terminal Type And Quantity:** 10 ribbon Shelf Life: N/a **Unit Of Measure: Demilitarization:** No